

2.0A/1.5A LDO REGULATOR

NO. EA-125-111027

OUTLINE

The R1171x Series are CMOS-based positive voltage regulator ICs. The R1171x Series have features of low dropout voltage, high output voltage accuracy, low consumption current. Each of these ICs consists of a voltage reference unit, an error amplifier, resistor net for setting output voltage, a current limit circuit at short mode, a chip enable circuit, and thermal shutdown circuit. The output voltage of R1171 is fixed in the IC.

Low consumption current by the merit of CMOS process and built-in transistors with low ON-resistance make low dropout voltage and chip enable function prolongs the battery life. These regulators are remarkable improvement on the current regulators in terms of input transient response, and load transient response.

Thus, the R1171x Series are suitable for various power sources.

Since the packages for these ICs are high wattage HSOP-6J package, TO-252-5-P1, high density mounting of the ICs on boards is possible.

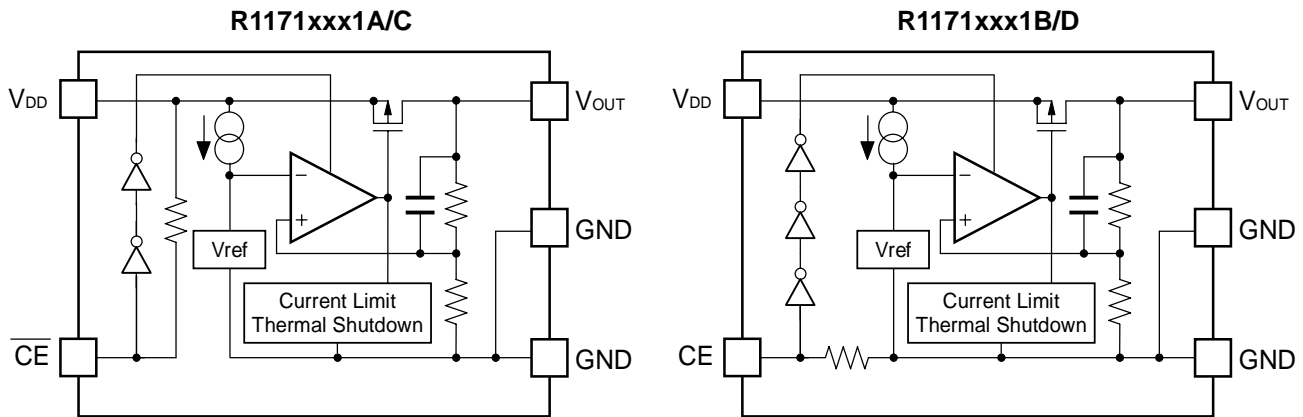
FEATURES

- Supply Current Typ. 130 μ A
- Standby Current Typ. 0.1 μ A
- Output Current Min. 1.5A ($V_{IN}=V_{OUT}+1.0V$, R1171Sxx1A/B)
Min. 2.0A ($V_{IN}=V_{OUT}+1.0V$, R1171Jxx1C/D)
- Input Voltage 2.1V to 6.0V
- Output Voltage 1.5V to 5.0V (0.1V steps) (R1171Sxx1A/B)
1.8V to 5.0V (0.1V steps) (R1171Jxx1C/D)
(For other voltages, please refer to MARK INFORMATIONS.)
- Output Voltage Accuracy..... $\pm 2.0\%$
- Dropout Voltage Typ. 0.09V ($V_{OUT}=3.0V$, $I_{OUT}=300mA$)
- Temperature-drift Coefficient of Output Voltage..... Typ. $\pm 100ppm/^{\circ}C$
- Line Regulation Typ. 0.05%/V
- Packages HSOP-6J, TO-252-5-P1
- Built-in Current Limit Circuit
- Built-in Thermal Shutdown Circuit
- Ceramic capacitor for phase compensation $C_{IN}=C_{OUT}=\text{Ceramic } 10\mu F$ ($V_{OUT}<1.8V$)
 $C_{IN}=C_{OUT}=\text{Ceramic } 4.7\mu F$ ($V_{OUT} \geq 1.8V$)

APPLICATIONS

- Local Power source for Notebook PC.
- Local Power source for portable appliances, cameras, and videos.
- Local Power source for equipment of battery-use.
- Local Power source for home appliances.

BLOCK DIAGRAMS



SELECTION GUIDE

The output voltage, chip enable polarity, package for the ICs can be selected at the user's request.

| Product Name | Package | Quantity per Reel | Pb Free | Halogen Free |
|------------------|-------------|-------------------|---------|--------------|
| R1171Sxx1*-E2-FE | HSOP-6J | 1,000 pcs | Yes | Yes |
| R1171Jyy1\$-T1-F | TO-252-5-P1 | 3,000 pcs | Yes | No |

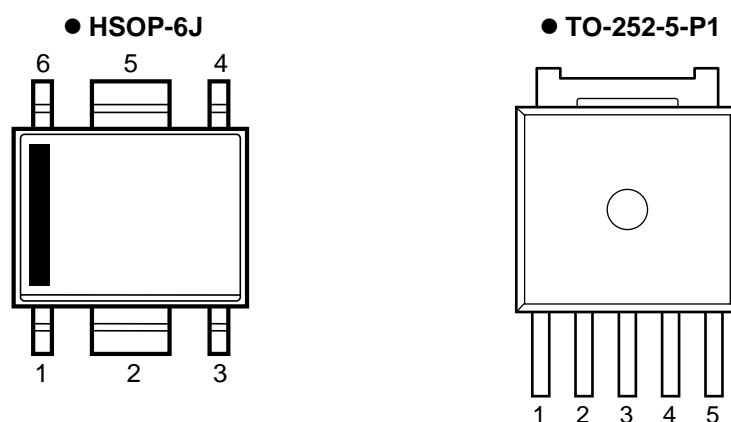
xx: The output voltage can be designated in the range from 1.5V(15) to 5.0V(50) in 0.1V steps.
(For other voltages, please refer to MARK INFORMATIONS.)

yy: The output voltage can be designated in the range from 1.8V(18) to 5.0V(50) in 0.1V steps.
(For other voltages, please refer to MARK INFORMATIONS.)

* : CE pin polarity are options as follows.
(A) "L" active
(B) "H" active

\$: CE pin polarity are options as follows.
(C) "L" active
(D) "H" active

PIN CONFIGURATIONS



PIN DESCRIPTIONS

• HSOP-6J

| Pin No | Symbol | Pin Description |
|--------|-----------------------|-----------------|
| 1 | V_{OUT} | Output Pin |
| 2 | GND | Ground Pin |
| 3 | \overline{CE} or CE | Chip Enable Pin |
| 4 | NC | No Connection |
| 5 | GND | Ground Pin |
| 6 | V_{DD} | Input Pin |

• TO-252-5-P1

| Pin No | Symbol | Pin Description |
|--------|-----------------------|-----------------|
| 1 | V_{OUT} | Output Pin |
| 2 | \overline{CE} or CE | Chip Enable Pin |
| 3 | GND | Ground Pin |
| 4 | GND | Ground Pin |
| 5 | V_{DD} | Input Pin |

*) No.3 and No.4 pins must be wired short each other and connected to the GND plane when it is mounted on board.

ABSOLUTE MAXIMUM RATINGS

| Symbol | Item | Rating | Unit |
|-----------|--|----------------------|------|
| V_{IN} | Input Voltage | 7.0 | V |
| V_{CE} | Input Voltage (\overline{CE} or CE Input Pin) | -0.3 to $V_{IN}+0.3$ | V |
| V_{OUT} | Output Voltage | -0.3 to $V_{IN}+0.3$ | V |
| P_D | Power Dissipation (HSOP-6J)* ¹ | 1700 | mW |
| | Power Dissipation (TO-252-5-P1)* ¹ | 1900 | |
| T_{opt} | Operating Temperature | -40 to 85 | °C |
| T_{stg} | Storage Temperature | -55 to 125 | °C |

*) For Power Dissipation, please refer to PACKAGE INFORMATION.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field.

The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

ELECTRICAL CHARACTERISTICS

• R1171Sxx1A

T_{opt}=25°C

| Symbol | Item | Conditions | Min. | Typ. | Max. | Unit | |
|---|---|---|------------------------------|------|-----------------|--------|---|
| V _{OUT} | Output Voltage | V _{IN} -V _{OUT} =1.0V, I _{OUT} =200mA | ×0.98 | | ×1.02 | V | |
| $\frac{\Delta V_{OUT}}{\Delta I_{OUT}}$ | Load Regulation | V _{IN} -V _{OUT} =1.0V 1mA ≤ I _{OUT} ≤ 300mA | | 10 | 60 | mV | |
| V _{DIF} | Dropout Voltage | I _{OUT} =300mA | 1.5 ≤ V _{OUT} <1.6 | | 0.16 | 0.35 | V |
| | | | 1.6 ≤ V _{OUT} <1.7 | | 0.14 | 0.32 | |
| | | | 1.7 ≤ V _{OUT} <1.8 | | 0.13 | 0.28 | |
| | | | 1.8 ≤ V _{OUT} <2.0 | | 0.12 | 0.24 | |
| | | | 2.0 ≤ V _{OUT} <2.5 | | 0.10 | 0.21 | |
| | | | 2.5 ≤ V _{OUT} ≤ 5.0 | | 0.09 | 0.18 | |
| I _{SS} | Supply Current | V _{IN} -V _{OUT} =1.0V, V _{CE} =0V | | 130 | 320 | μA | |
| I _{standby} | Standby Current | V _{IN} -V _{OUT} =1.0V, V _{IN} =V _{CE} | | 0.1 | 2.0 | μA | |
| $\frac{\Delta V_{OUT}}{\Delta V_{IN}}$ | Line Regulation | I _{OUT} =200mA | Refer to the following table | | | | |
| RR | Ripple Rejection | f=1kHz, Ripple 0.5Vp-p | | | | | |
| V _{IN} | Input Voltage | | 2.1 | | 6.0 | V | |
| $\frac{\Delta V_{OUT}}{\Delta T_{opt}}$ | Output Voltage Temperature Coefficient | I _{OUT} =10mA -40°C ≤ T _{opt} ≤ 85°C | | ±100 | | ppm/°C | |
| I _{LIM} | Output Current | V _{IN} -V _{OUT} =1.0V | 1.5 | | | A | |
| I _{SC} | Short Current Limit | V _{OUT} =0V | | 200 | | mA | |
| R _{PU} | Pull-up resistance for \overline{CE} pin | | 2.5 | 5.0 | 10.0 | MΩ | |
| V _{CEH} | \overline{CE} Input Voltage "H" | | 1.2 | | V _{IN} | V | |
| V _{CEL} | \overline{CE} Input Voltage "L" | | 0 | | 0.25 | V | |
| T _{TSD} | Thermal Shutdown Detector Threshold Temperature | Junction Temperature | | 150 | | °C | |
| T _{TSR} | Thermal Shutdown Released Temperature | Junction Temperature | | 120 | | °C | |

• Line Regulation by Output Voltage

T_{opt}=25°C

| Output Voltage V _{OUT} (V) | Line Regulation $\Delta V_{OUT}/\Delta V_{IN}$ (%/V) | | |
|--|--|------|------|
| | Condition | Typ. | Max. |
| 1.5 ≤ V _{OUT} < 1.6 | I _{OUT} =200mA, 2.1V ≤ V _{IN} ≤ 6.0V | 0.05 | 0.30 |
| 1.6 ≤ V _{OUT} ≤ 5.0 | | | |

• Ripple Rejection by Output Voltage

T_{opt}=25°C

| Output Voltage V _{OUT} (V) | Ripple Rejection RR (dB) | |
|--|---|------|
| | Condition | Typ. |
| 1.5 ≤ V _{OUT} < 4.7 | f=1kHz, Ripple 0.5Vp-p, V _{IN} -V _{OUT} =1.0V | 50 |
| 4.7 ≤ V _{OUT} ≤ 5.0 | | |

R1171x

• R1171Sxx1B

T_{opt}=25°C

| Symbol | Item | Conditions | Min. | Typ. | Max. | Unit | |
|--------------------------------------|--|---|------------------------------|------------------------------|-----------------|--------|---|
| V _{OUT} | Reference Voltage for Adjustable Voltage Regulator | V _{IN} -V _{OUT} =1.0V I _{OUT} =200mA | ×0.98 | | ×1.02 | V | |
| ΔV _{OUT} /ΔI _{OUT} | Load Regulation | V _{IN} -V _{OUT} =1.0V 1mA ≤ I _{OUT} ≤ 300mA | | 10 | 60 | mV | |
| V _{DIF} | Dropout Voltage | I _{OUT} =300mA | | 1.5 ≤ V _{OUT} <1.6 | 0.16 | 0.35 | V |
| | | | | 1.6 ≤ V _{OUT} <1.7 | 0.14 | 0.32 | |
| | | | | 1.7 ≤ V _{OUT} <1.8 | 0.13 | 0.28 | |
| | | | | 1.8 ≤ V _{OUT} <2.0 | 0.12 | 0.24 | |
| | | | | 2.0 ≤ V _{OUT} <2.5 | 0.10 | 0.21 | |
| | | | | 2.5 ≤ V _{OUT} ≤ 5.0 | 0.09 | 0.18 | |
| I _{SS} | Supply Current | V _{IN} -V _{OUT} =1.0V, V _{CE} =V _{IN} | | 130 | 320 | μA | |
| I _{standby} | Standby Current | V _{IN} -V _{OUT} =1.0V, V _{CE} =0V | | 0.1 | 2.0 | μA | |
| ΔV _{OUT} /ΔV _{IN} | Line Regulation | I _{OUT} =200mA | Refer to the following table | | | | |
| RR | Ripple Rejection | f=1kHz, Ripple 0.5Vp-p | | | | | |
| V _{IN} | Input Voltage | | 2.1 | | 6.0 | V | |
| ΔV _{OUT} /ΔT _{opt} | Output Voltage Temperature Coefficient | I _{OUT} =10mA -40°C ≤ T _{opt} ≤ 85°C | | ±100 | | ppm/°C | |
| I _{LIM} | Output Current | V _{IN} -V _{OUT} =1.0V | 1.5 | | | A | |
| I _{SC} | Short Current Limit | V _{OUT} =0V | | 200 | | mA | |
| R _{PD} | Pull-down resistance for CE pin | | 2.5 | 5.0 | 10.0 | MΩ | |
| V _{CEH} | CE Input Voltage "H" | | 1.2 | | V _{IN} | V | |
| V _{CEL} | CE Input Voltage "L" | | 0 | | 0.25 | V | |
| T _{TSD} | Thermal Shutdown Detector Threshold Temperature | Junction Temperature | | 150 | | °C | |
| T _{TSR} | Thermal Shutdown Released Temperature | Junction Temperature | | 120 | | °C | |

• Line Regulation by Output Voltage

T_{opt}=25°C

| Output Voltage V _{OUT} (V) | Line Regulation ΔV _{OUT} /ΔV _{IN} (%/V) | | |
|--|---|------|------|
| | Condition | Typ. | Max. |
| 1.5 ≤ V _{OUT} < 1.6 | I _{OUT} =200mA, 2.1V ≤ V _{IN} ≤ 6.0V | 0.05 | 0.30 |
| 1.6 ≤ V _{OUT} ≤ 5.0 | | | |

• Ripple Rejection by Output Voltage

T_{opt}=25°C

| Output Voltage V _{OUT} (V) | Ripple Rejection RR (dB) | |
|--|---|------|
| | Condition | Typ. |
| 1.5 ≤ V _{OUT} < 4.7 | f=1kHz, Ripple 0.5Vp-p, V _{IN} -V _{OUT} =1.0V | 50 |
| 4.7 ≤ V _{OUT} ≤ 5.0 | | |

- R1171Jxx1C

T_{opt}=25°C

| Symbol | Item | Conditions | Min. | Typ. | Max. | Unit |
|--|---|---|------------------------------|------|-----------------|--------|
| V _{OUT} | Output Voltage | V _{IN} -V _{OUT} =1.0V I _{OUT} =200mA | ×0.98 | | ×1.02 | V |
| ΔV _{OUT} / ΔI _{OUT} | Load Regulation | V _{IN} -V _{OUT} =1.0V 1mA ≤ I _{OUT} ≤ 300mA | | 10 | 60 | mV |
| V _{DIF} | Dropout Voltage | I _{OUT} =300mA | 1.8 ≤ V _{OUT} <2.0 | 0.12 | 0.24 | V |
| | | | 2.0 ≤ V _{OUT} <2.5 | 0.10 | 0.21 | |
| | | | 2.5 ≤ V _{OUT} ≤ 5.0 | 0.09 | 0.18 | |
| I _{SS} | Supply Current | V _{IN} -V _{OUT} =1.0V, V _{CE} =0V | | 130 | 320 | μA |
| I _{standby} | Standby Current | V _{IN} -V _{OUT} =1.0V, V _{IN} =V _{CE} | | 0.1 | 2.0 | μA |
| ΔV _{OUT} / ΔV _{IN} | Line Regulation | I _{OUT} =200mA V _{OUT} +0.5V ≤ V _{IN} ≤ 6V | | 0.05 | 0.30 | %/V |
| RR | Ripple Rejection | f=1kHz, Ripple 0.5Vp-p | Refer to the following table | | | |
| V _{IN} | Input Voltage | | 2.1 | | 6.0 | V |
| ΔV _{OUT} / ΔT _{opt} | Output Voltage Temperature Coefficient | I _{OUT} =10mA -40°C ≤ T _{opt} ≤ 85°C | | ±100 | | ppm/°C |
| I _{LIM} | Output Current | V _{IN} -V _{OUT} =1.0V | 2.0 | | | A |
| I _{SC} | Short Current Limit | V _{OUT} =0V | | 200 | | mA |
| R _{PU} | Pull-up resistance for \overline{CE} pin | | 2.5 | 5.0 | 10.0 | MΩ |
| V _{CEH} | \overline{CE} Input Voltage "H" | | 1.2 | | V _{IN} | V |
| V _{CEL} | \overline{CE} Input Voltage "L" | | 0 | | 0.25 | V |
| T _{TSD} | Thermal Shutdown Detector Threshold Temperature | Junction Temperature | | 150 | | °C |
| T _{TSR} | Thermal Shutdown Released Temperature | Junction Temperature | | 120 | | °C |

- Ripple Rejection by Output Voltage

T_{opt}=25°C

| Output Voltage V _{OUT} (V) | Ripple Rejection RR (dB) | |
|--|---|------|
| | Condition | Typ. |
| 1.8 ≤ V _{OUT} < 4.7 | f=1kHz, Ripple 0.5Vp-p, V _{IN} -V _{OUT} =1.0V | 50 |
| 4.7 ≤ V _{OUT} ≤ 5.0 | f=1kHz, Ripple 0.5Vp-p, V _{IN} =5.75V | |

R1171x

• R1171Jxx1D

T_{opt}=25°C

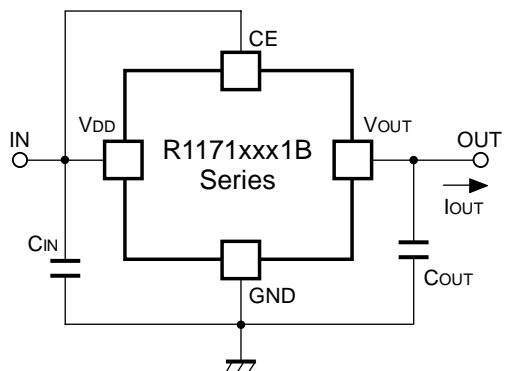
| Symbol | Item | Conditions | Min. | Typ. | Max. | Unit |
|--------------------------------------|--|---|------------------------------|------|-----------------|--------|
| V _{OUT} | Reference Voltage for Adjustable Voltage Regulator | V _{IN} -V _{OUT} =1.0V I _{OUT} =200mA | ×0.98 | | ×1.02 | V |
| ΔV _{OUT} /ΔI _{OUT} | Load Regulation | V _{IN} -V _{OUT} =1.0V 1mA ≤ I _{OUT} ≤ 300mA | | 10 | 60 | mV |
| V _{DIF} | Dropout Voltage | I _{OUT} =300mA | 1.8 ≤ V _{OUT} <2.0 | 0.12 | 0.24 | V |
| | | | 2.0 ≤ V _{OUT} <2.5 | 0.10 | 0.21 | |
| | | | 2.5 ≤ V _{OUT} ≤ 5.0 | 0.09 | 0.18 | |
| I _{SS} | Supply Current | V _{IN} -V _{OUT} =1.0V, V _{CE} =V _{IN} | | 130 | 320 | μA |
| I _{standby} | Standby Current | V _{IN} -V _{OUT} =1.0V, V _{CE} =0V | | 0.1 | 2.0 | μA |
| ΔV _{OUT} /ΔV _{IN} | Line Regulation | I _{OUT} =200mA V _{OUT} +0.5V ≤ V _{IN} ≤ 6V | | 0.05 | 0.30 | %/V |
| RR | Ripple Rejection | f=1kHz, Ripple 0.5Vp-p | Refer to the following table | | | |
| V _{IN} | Input Voltage | | 2.1 | | 6.0 | V |
| ΔV _{OUT} /ΔT _{opt} | Output Voltage Temperature Coefficient | I _{OUT} =10mA -40°C ≤ T _{opt} ≤ 85°C | | ±100 | | ppm/°C |
| I _{LIM} | Output Current | V _{IN} -V _{OUT} =1.0V | 2.0 | | | A |
| I _{SC} | Short Current Limit | V _{OUT} =0V | | 200 | | mA |
| R _{PD} | Pull-down resistance for CE pin | | 2.5 | 5.0 | 10.0 | MΩ |
| V _{CEH} | CE Input Voltage "H" | | 1.2 | | V _{IN} | V |
| V _{CEL} | CE Input Voltage "L" | | 0 | | 0.25 | V |
| T _{TSD} | Thermal Shutdown Detector Threshold Temperature | Junction Temperature | | 150 | | °C |
| T _{TSR} | Thermal Shutdown Released Temperature | Junction Temperature | | 120 | | °C |

• Ripple Rejection by Output Voltage

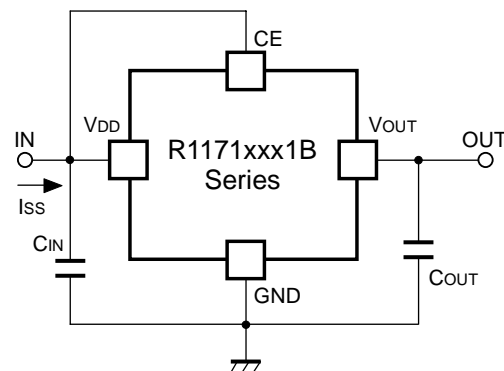
T_{opt}=25°C

| Output Voltage V _{OUT} (V) | Ripple Rejection RR (dB) | |
|--|---|------|
| | Condition | Typ. |
| 1.8 ≤ V _{OUT} < 4.7 | f=1kHz, Ripple 0.5Vp-p, V _{IN} -V _{OUT} =1.0V | 50 |
| 4.7 ≤ V _{OUT} ≤ 5.0 | f=1kHz, Ripple 0.5Vp-p, V _{IN} =5.75V | |

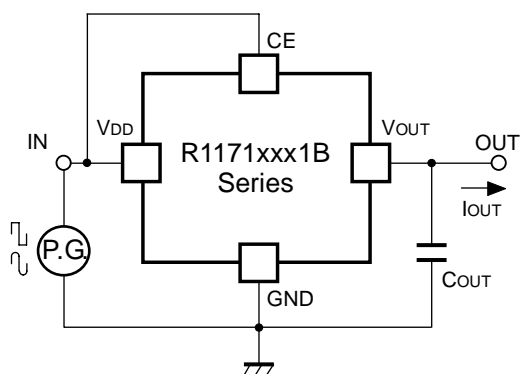
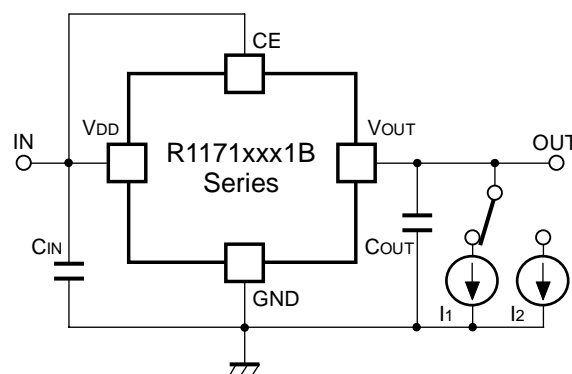
TEST CIRCUITS



Standard Test Circuit



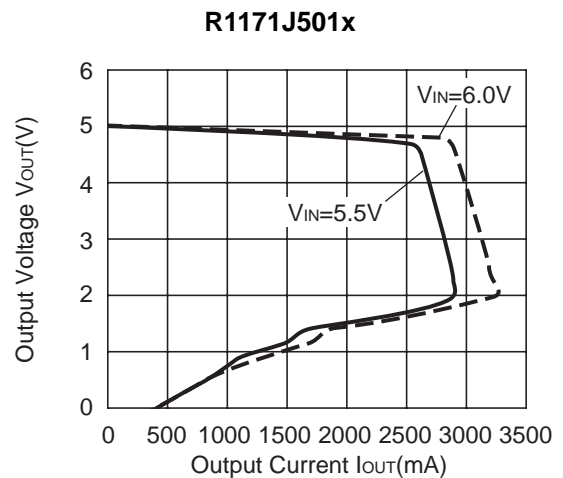
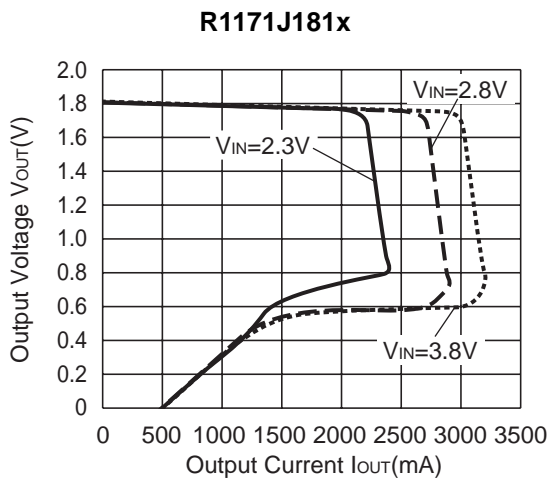
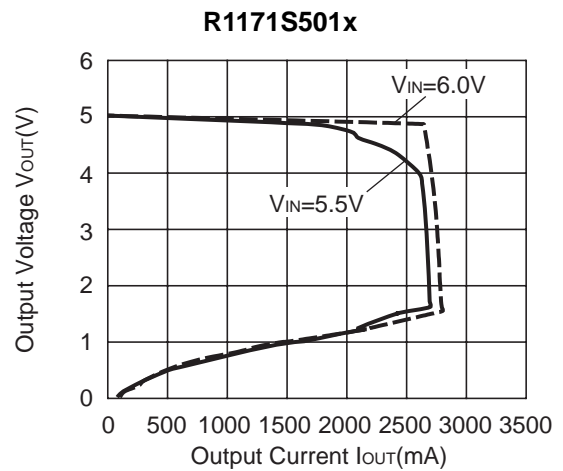
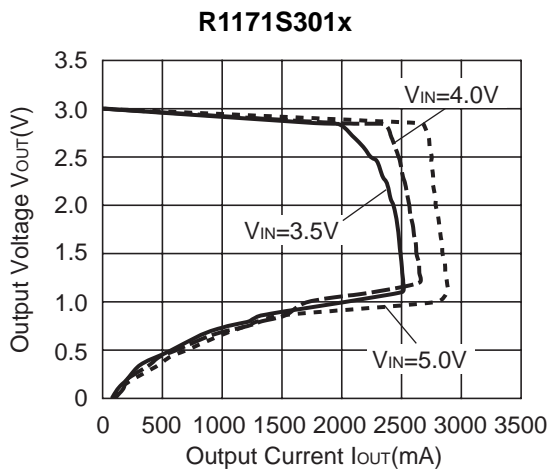
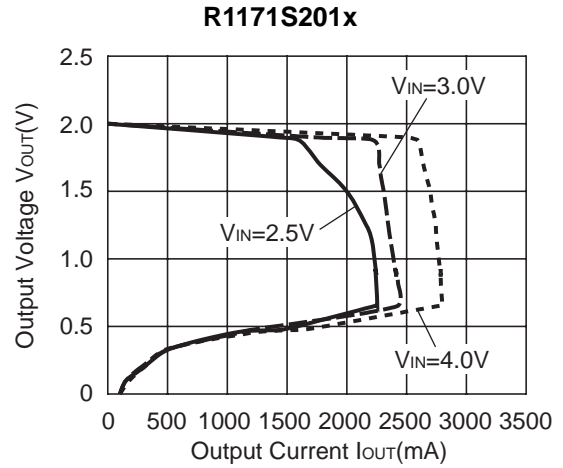
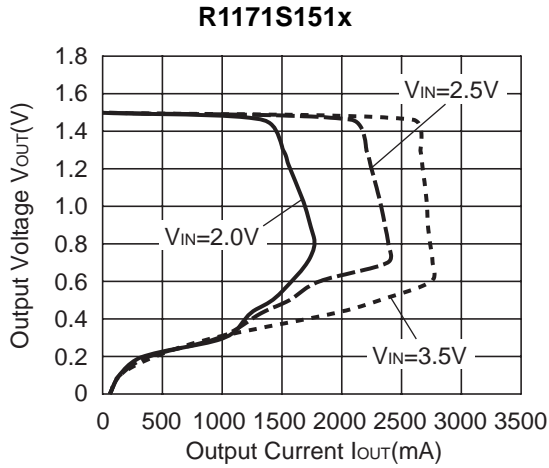
Supply Current Test Circuit

Test Circuit for Ripple Rejection,
Input Transient Response

Test Circuit for Load Transient Response

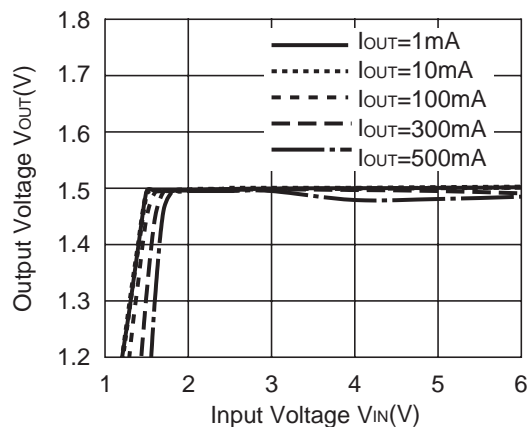
TYPICAL CHARACTERISTICS

1) Output Voltage vs. Output Current (Topt=25°C)

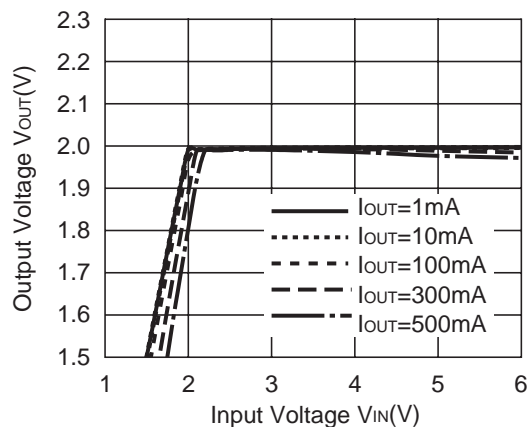


2) Output Voltage vs. Input Voltage ($T_{opt}=25^{\circ}\text{C}$)

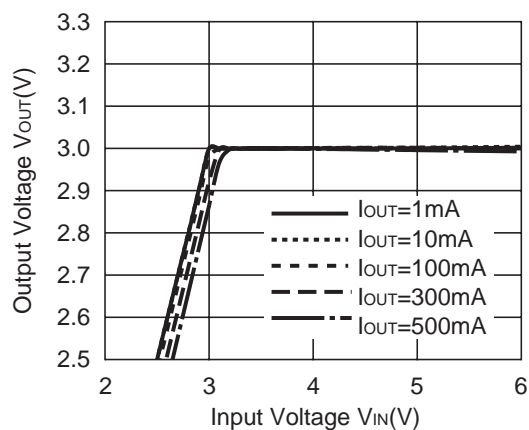
R1171x151B



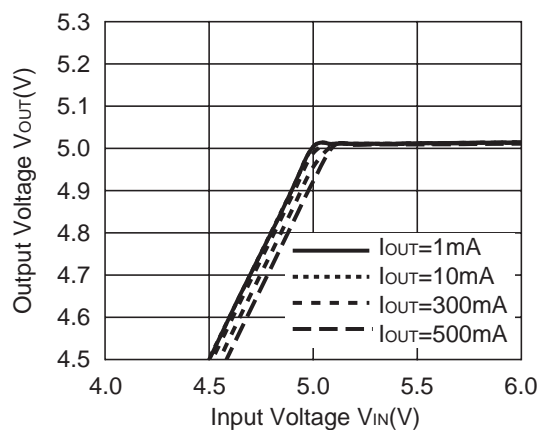
R1171x201B



R1171x301B

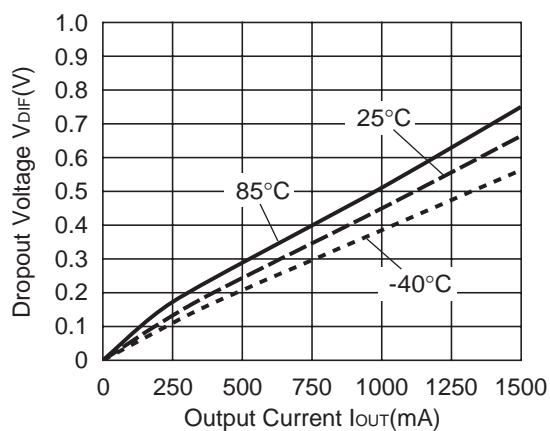


R1171x501B

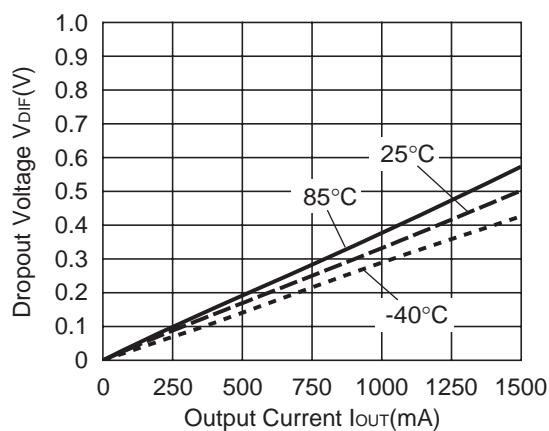


3) Dropout Voltage vs. Output Current

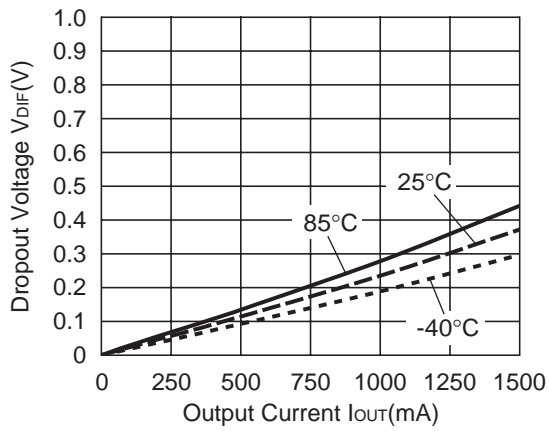
R1171S151x



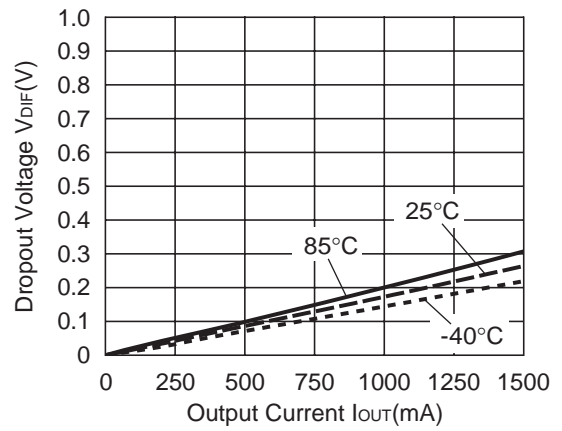
R1171S201x



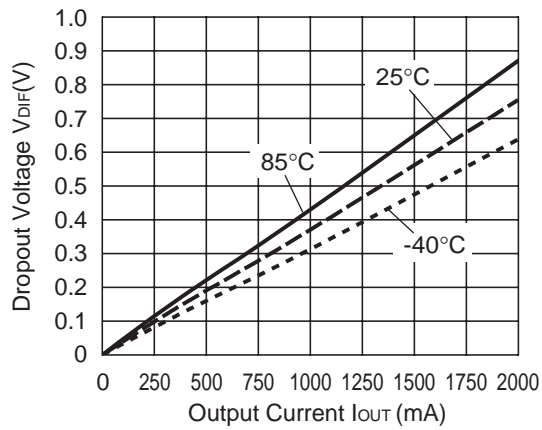
R1171S301x



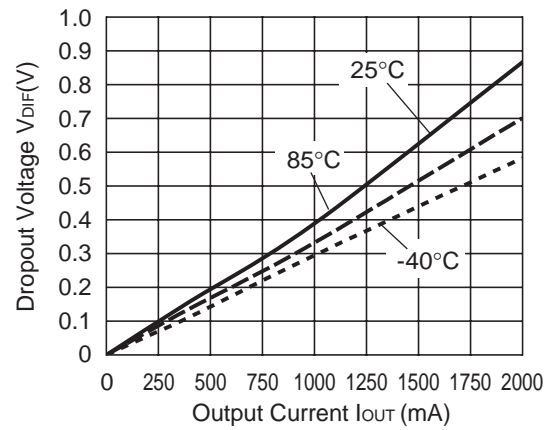
R1171S501x



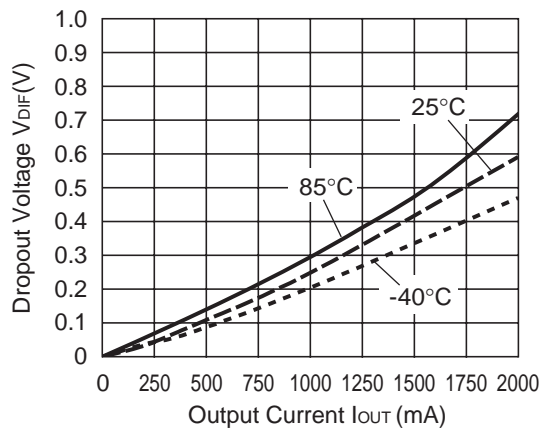
R1171J181x



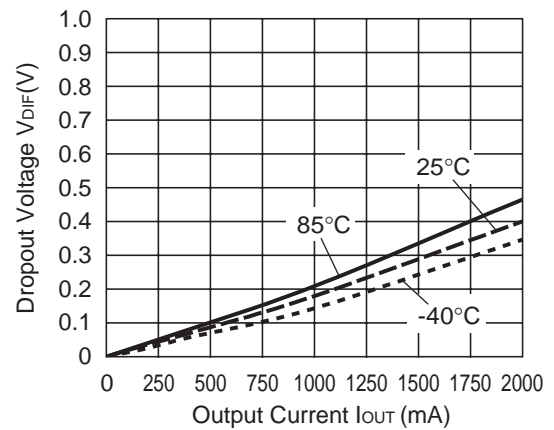
R1171J201x



R1171J301x

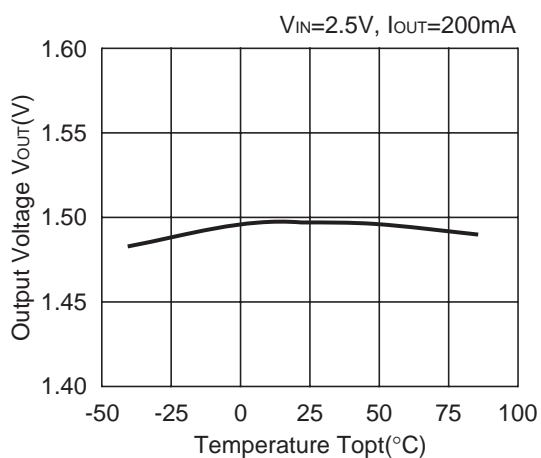


R1171J501x

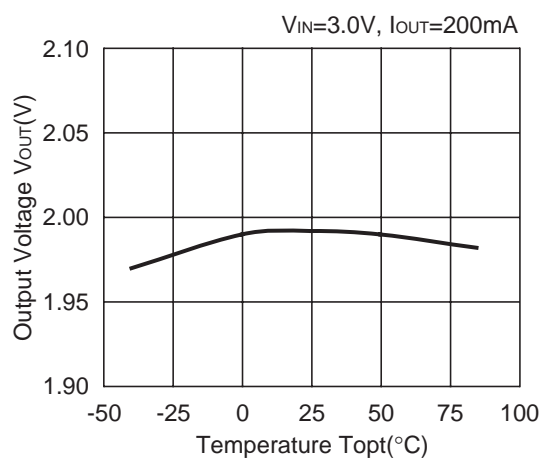


4) Output Voltage vs. Temperature

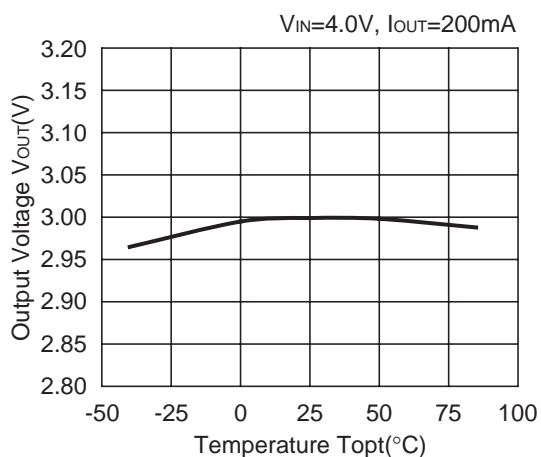
R1171x151B



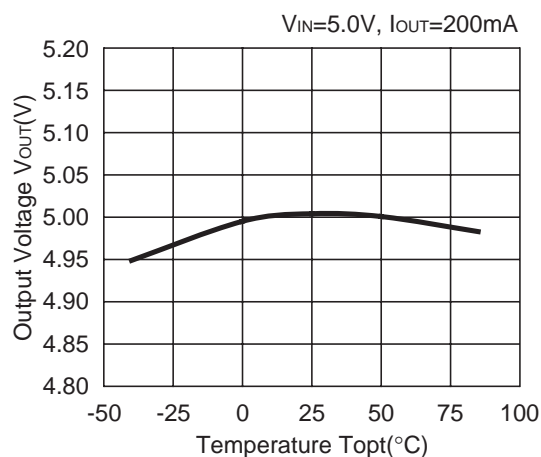
R1171x201B



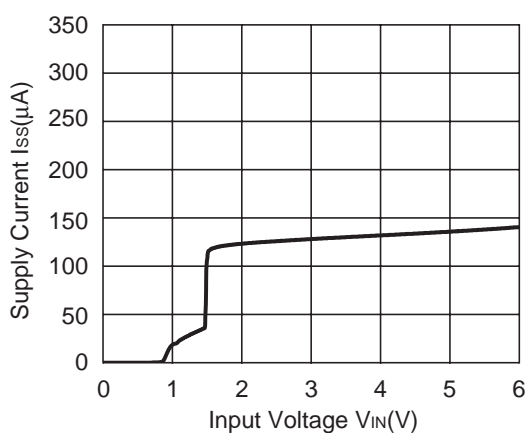
R1171x301B



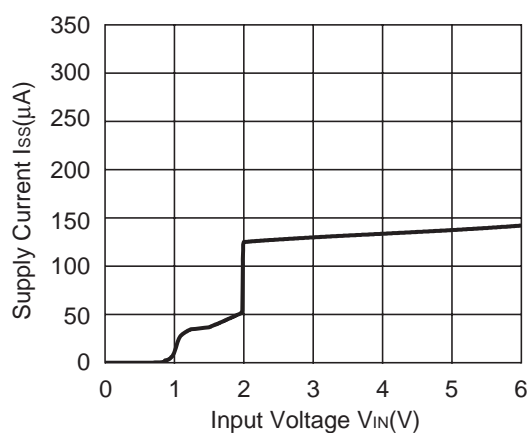
R1171x501B

5) Supply Current vs. Input Voltage ($T_{opt}=25^{\circ}C$)

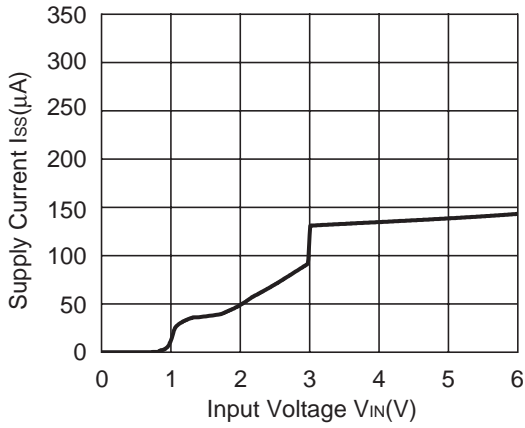
R1171x151B



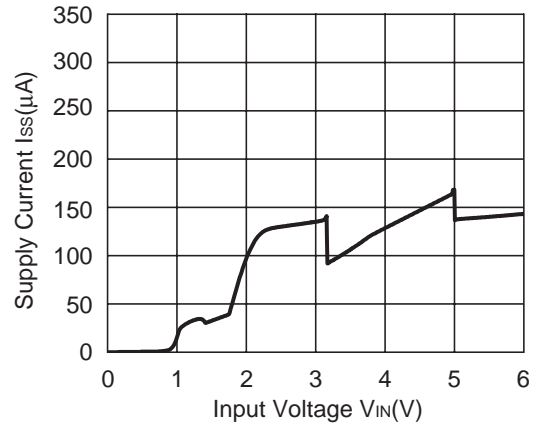
R1171x201B



R1171x301B

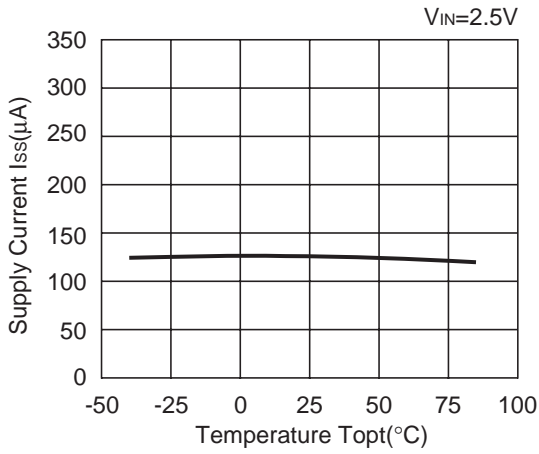


R1171x501B

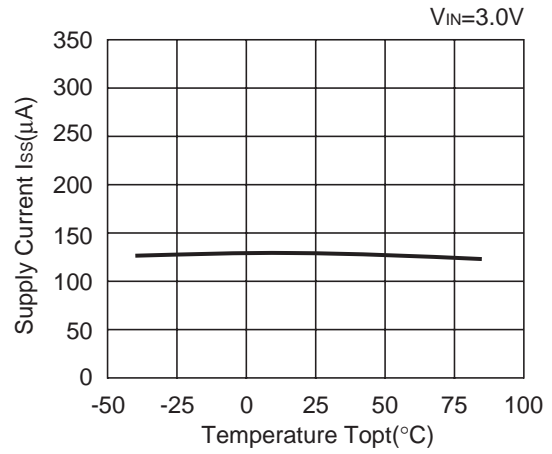


6) Supply Current vs. Temperature

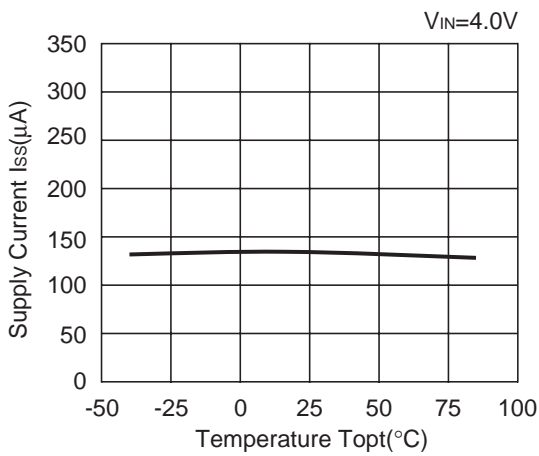
R1171x151B



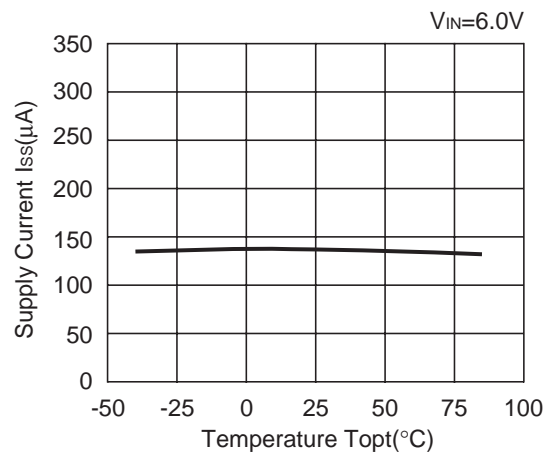
R1171x201B

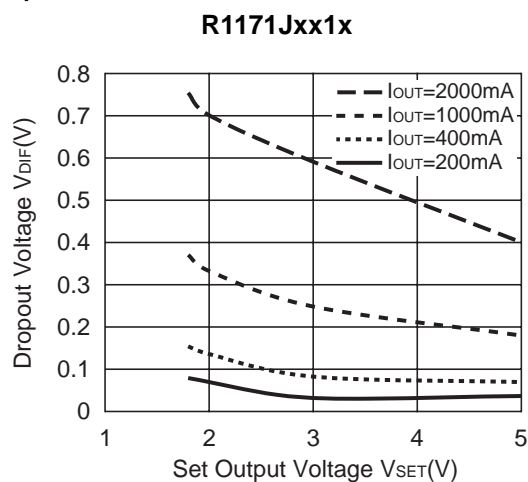
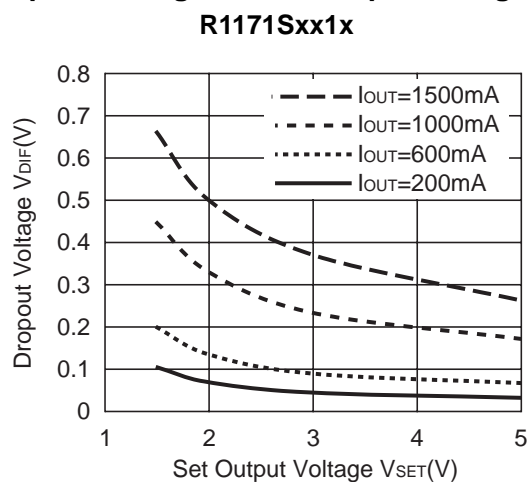


R1171x301B

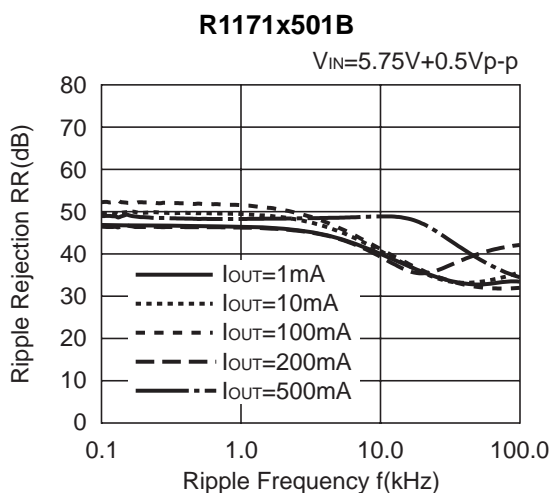
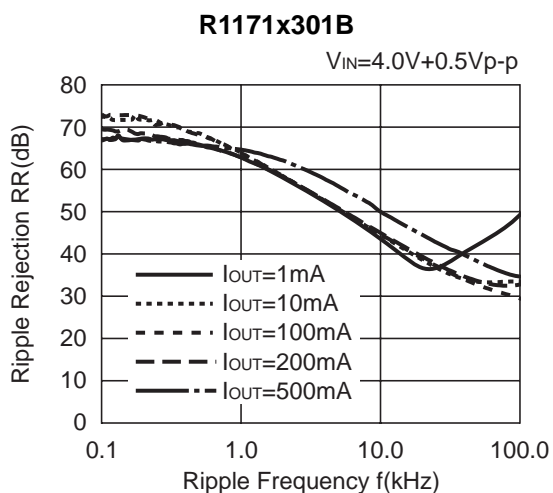
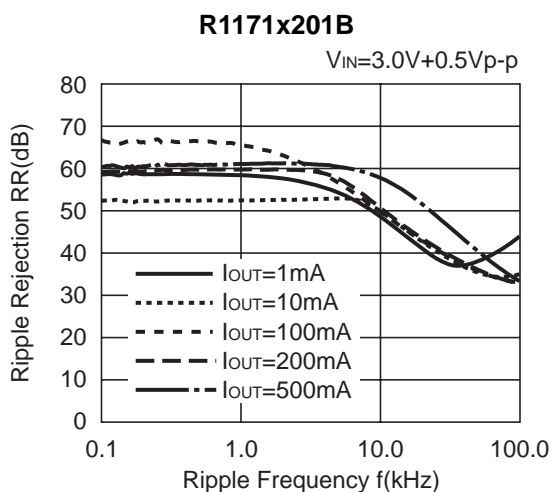
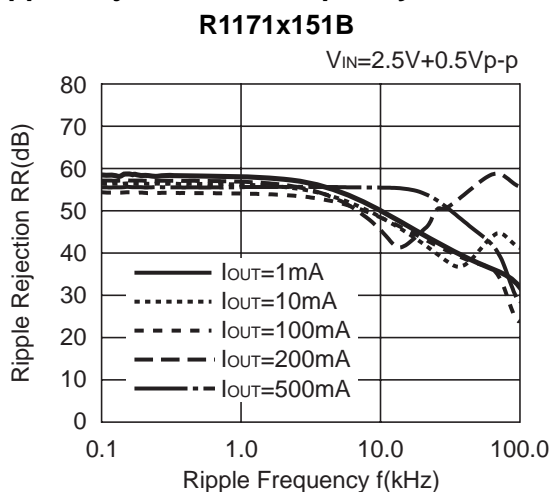


R1171x501B

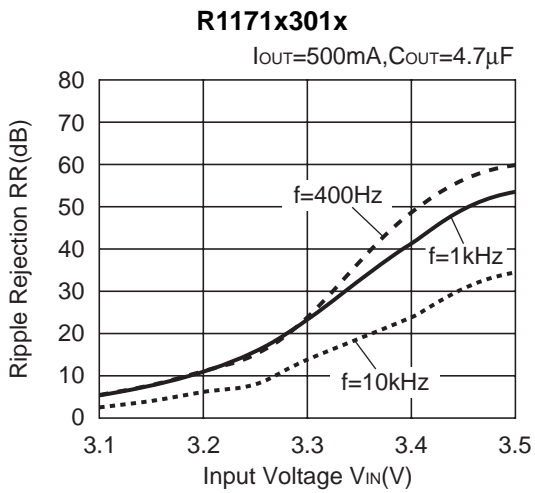
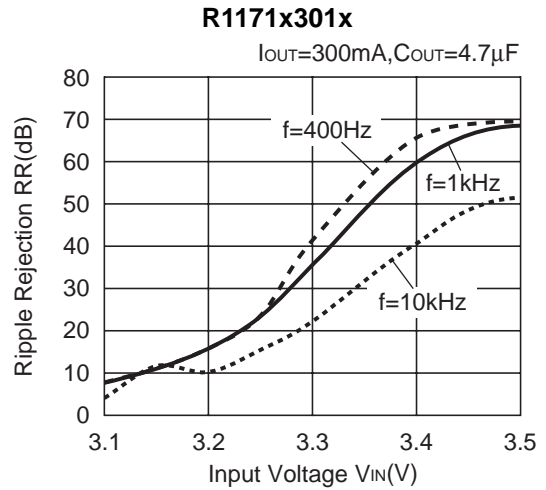
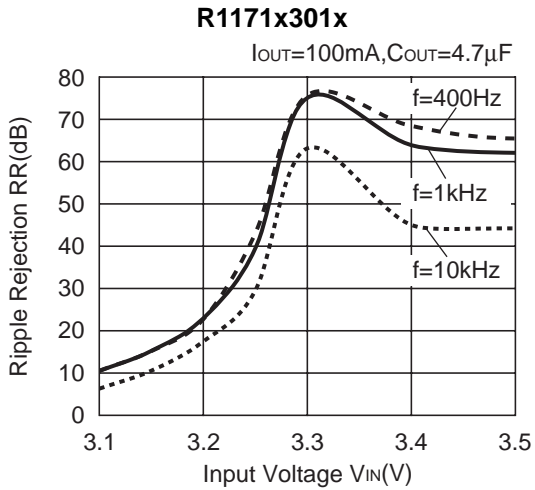
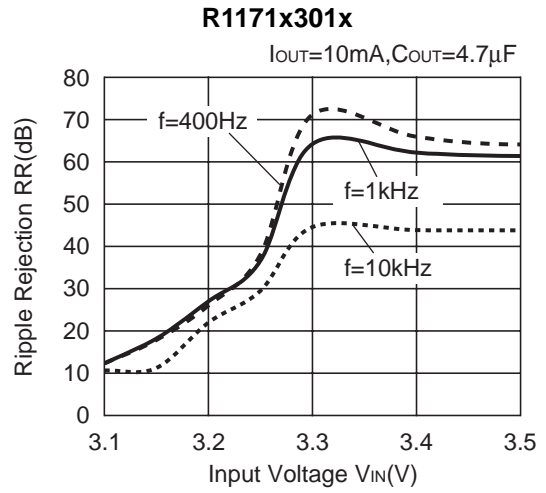
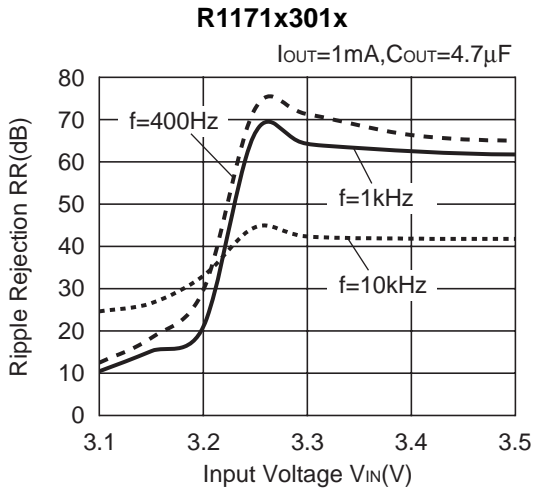


7) Dropout Voltage vs. Set Output Voltage ($T_{opt}=25^{\circ}\text{C}$)

8) Ripple Rejection vs. Frequency

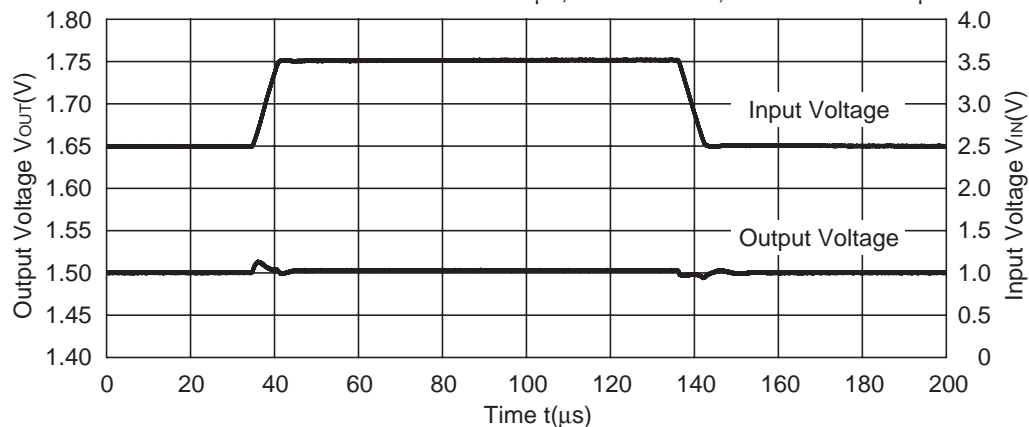


9) Ripple Rejection vs. Input Voltage

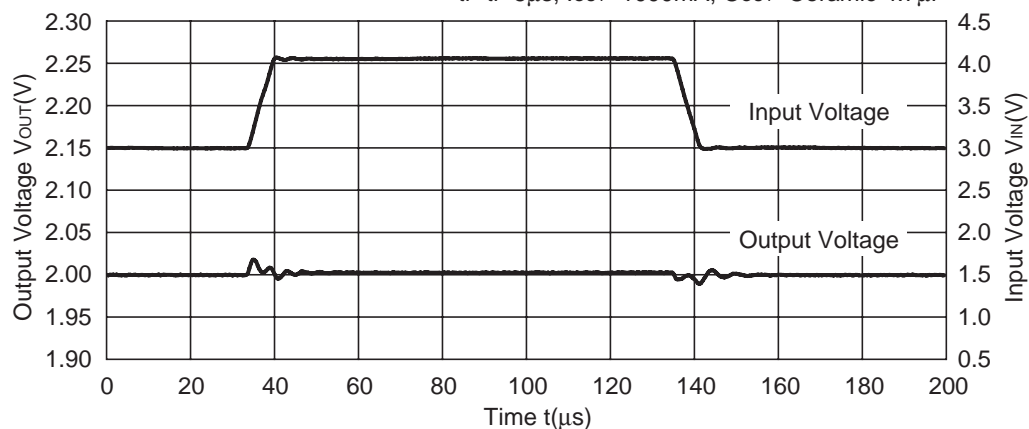


10) Input Transient Response ($T_{opt}=25^{\circ}\text{C}$)

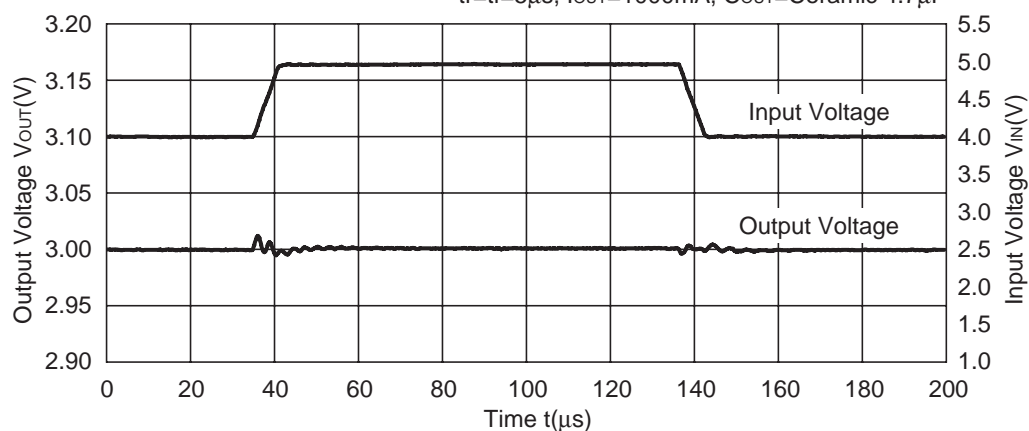
R1171x151B

 $t_r=t_f=5\mu\text{s}$, $I_{OUT}=1000\text{mA}$, $C_{OUT}=\text{Ceramic } 10\mu\text{F}$ 

R1171x201B

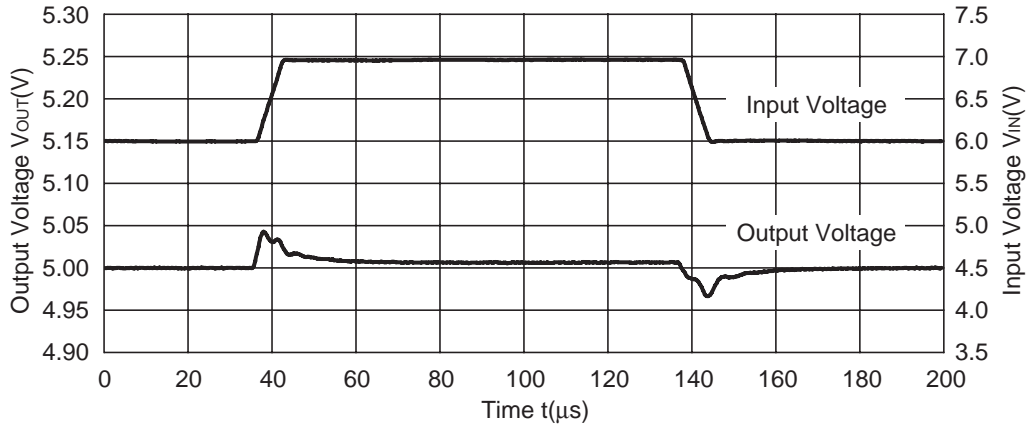
 $t_r=t_f=5\mu\text{s}$, $I_{OUT}=1000\text{mA}$, $C_{OUT}=\text{Ceramic } 4.7\mu\text{F}$ 

R1171x301B

 $t_r=t_f=5\mu\text{s}$, $I_{OUT}=1000\text{mA}$, $C_{OUT}=\text{Ceramic } 4.7\mu\text{F}$ 

R1171x501B

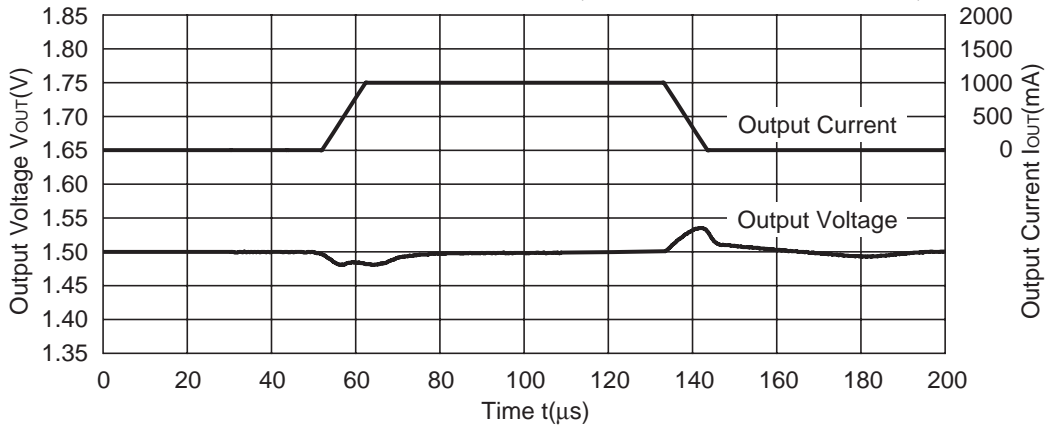
$t_r=t_f=5\mu s$, $I_{OUT}=1000mA$, $C_{OUT}=\text{Ceramic } 4.7\mu F$



11) Load Transient Response ($T_{opt}=25^{\circ}C$)

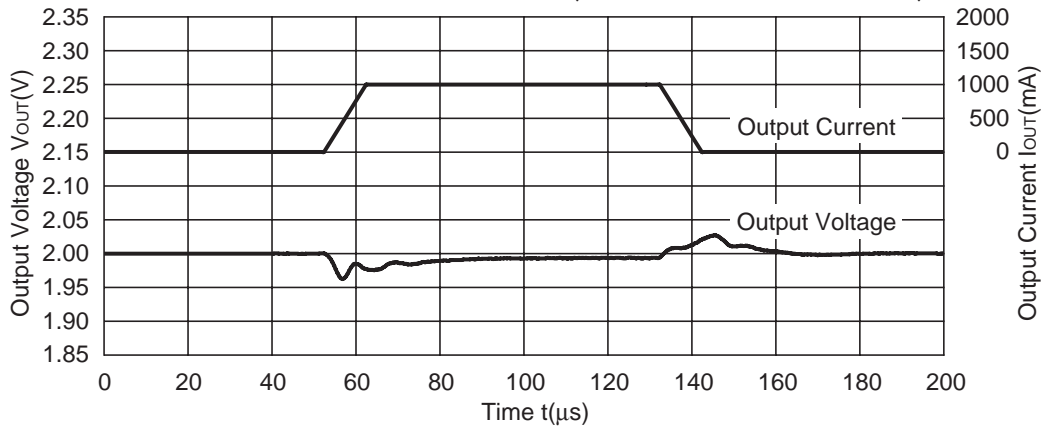
R1171x151B

$t_r=t_f=10\mu s$, $V_{IN}=2.5V$, $C_{OUT}=\text{Ceramic } 10\mu F$



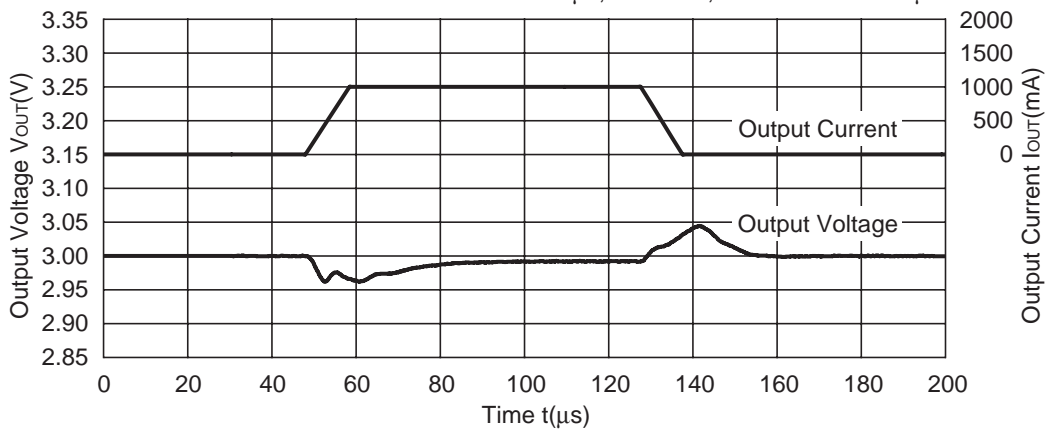
R1171x201B

$t_r=t_f=10\mu s$, $V_{IN}=3.0V$, $C_{OUT}=\text{Ceramic } 4.7\mu F$



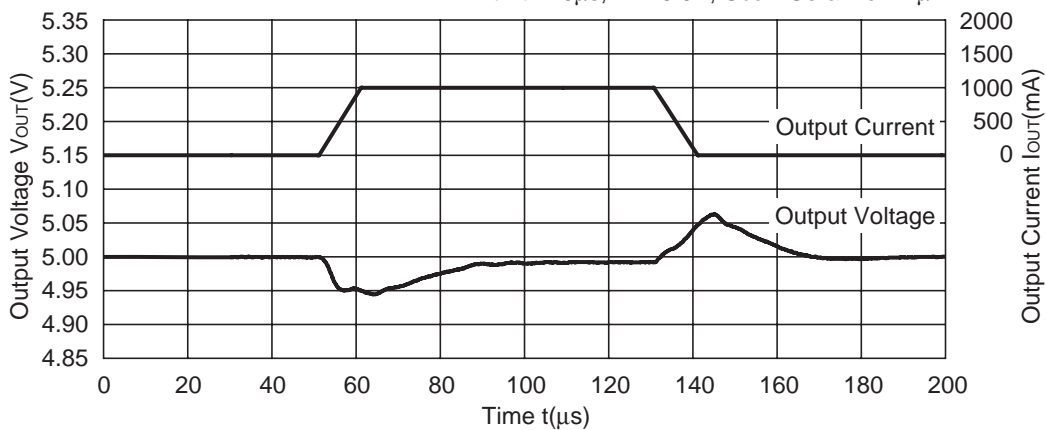
R1171x301B

$t_r=t_f=10\mu s$, $V_{IN}=4.0V$, $C_{OUT}=\text{Ceramic } 4.7\mu F$



R1171x501B

$t_r=t_f=10\mu s$, $V_{IN}=6.0V$, $C_{OUT}=\text{Ceramic } 4.7\mu F$



Technical Notes on External Components and Typical Application

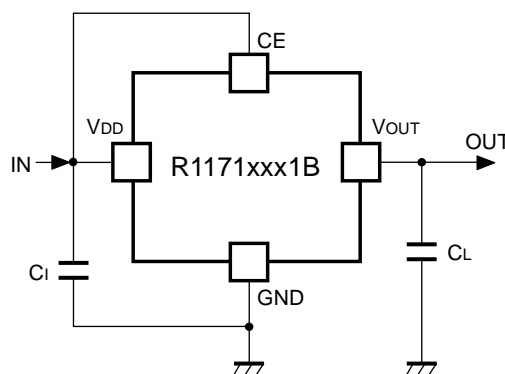
1. Phase Compensation

In these ICs, phase compensation is made with the output capacitor for securing stable operation even if the load current is varied. For this purpose, use a capacitor with the capacitance range from $4.7\mu\text{F}$ to $10.0\mu\text{F}$, as C_L . In case that using a tantalum capacitor and the ESR of the tantalum capacitor is too large, unstable operation may result. Fully evaluation is necessary for the whole circuit with considering the frequency characteristic.

2. Mounting on PCB

Make V_{DD} and GND lines sufficient. If their impedance is high, large current may flow and the pick-up noise or unstable operation may result. Therefore use a capacitor with a capacitance range from $4.7\mu\text{F}$ to $10.0\mu\text{F}$ between V_{DD} pin and GND pin as close as possible.

Further, set an output capacitor between V_{OUT} pin and GND pin for phase compensation as close as possible. (Refer to the example of typical application)



R1171Sxx1B Typical Application

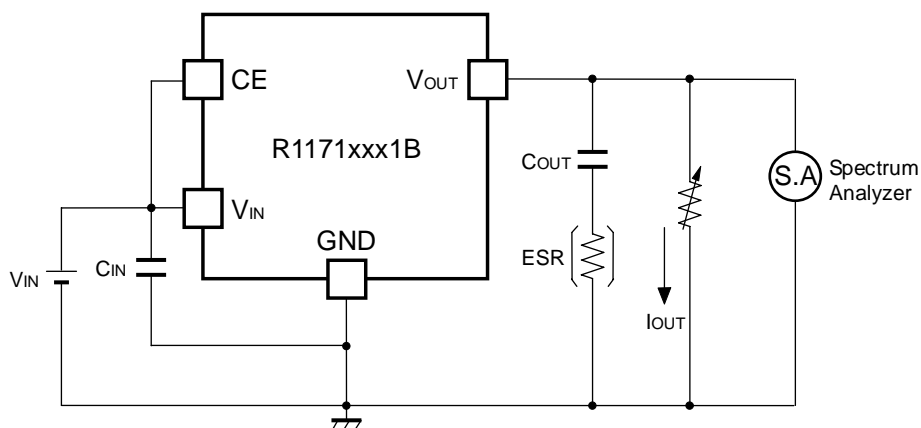
$1.5\text{V} \leq V_{OUT} < 1.8\text{V}$: $C_i=10\mu\text{F}$ (Ceramic), $C_L=10\mu\text{F}$ (Ceramic)

$1.8\text{V} \leq V_{OUT} \leq 5.0\text{V}$: $C_i=4.7\mu\text{F}$ (Ceramic), $C_L=4.7\mu\text{F}$ (Ceramic)

3. Output Short Protection Function

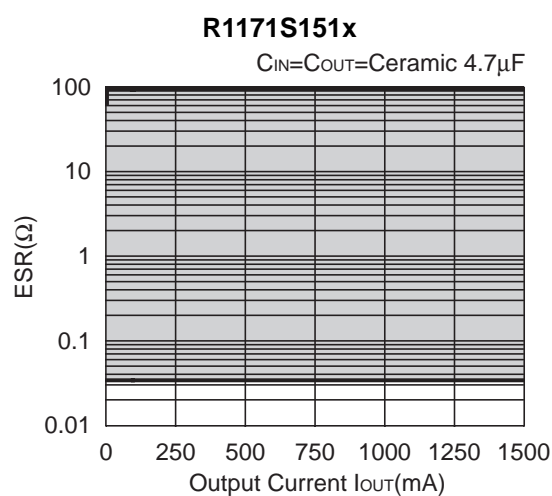
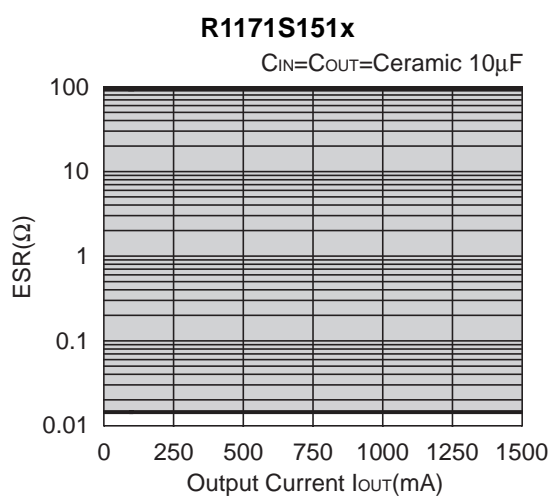
In the R1171x Series, the output short protection function is built in, further, if the output is short to the GND or other voltage line, the chip inside is heating, as a result, in case that the junction temperature becomes equal or more than 150°C (Typ.), the built-in thermal shutdown circuit works. If the junction temperature becomes equal or more than 150°C (Typ.), the IC is protected by the output short protection circuit and the thermal shutdown circuit.

ESR vs. Output Current (T_{opt}=25°C, V_{IN}=Set Output Voltage+1V, C_{IN}=Ceramic 10μF)



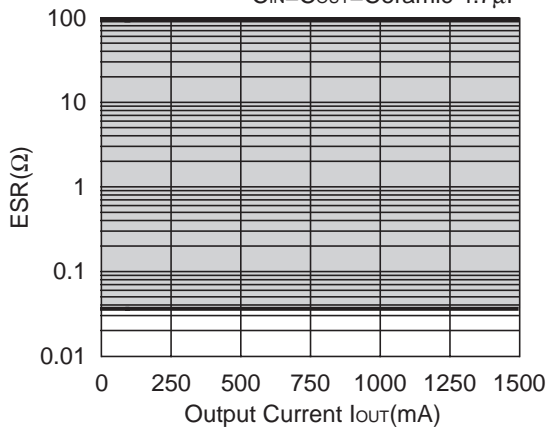
As an output capacitor for this IC, Ceramic capacitor is recommendable. However, other low ESR type capacitor can be used with this IC.

For your reference, noise level is tested with the circuit as shown above, and if the noise level is $40\mu\text{V}$ or less than $40\mu\text{V}$, the ESR values are plotted as stable area. Upper limit is described in the next four graphs, or ESR vs. Output Current. (Hatched area is the stable area.)



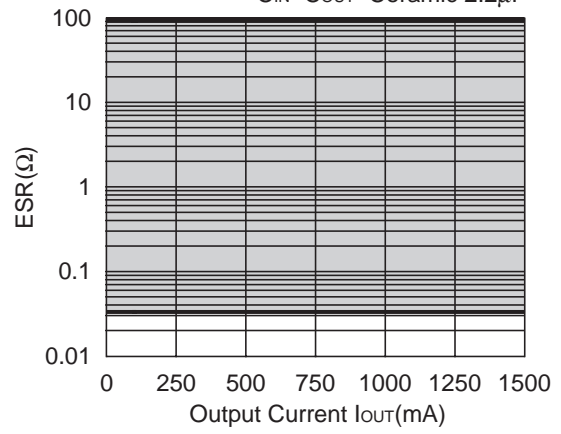
R1171S301x

$C_{IN}=C_{OUT}=\text{Ceramic } 4.7\mu\text{F}$



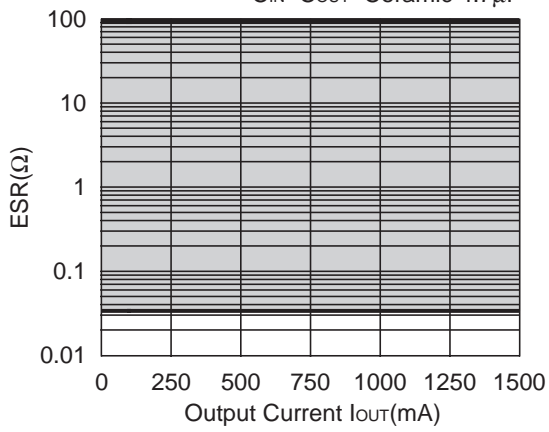
R1171S301x

$C_{IN}=C_{OUT}=\text{Ceramic } 2.2\mu\text{F}$



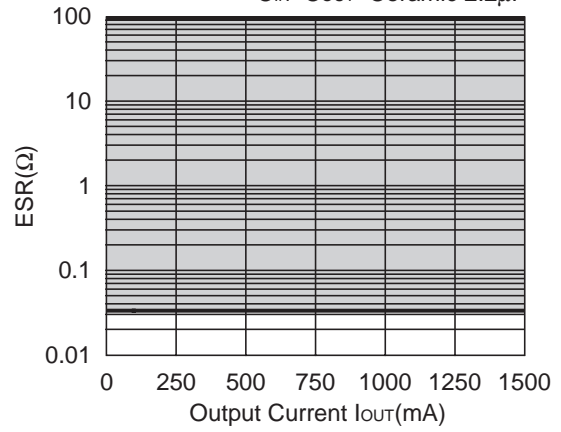
R1171S501x

$C_{IN}=C_{OUT}=\text{Ceramic } 4.7\mu\text{F}$



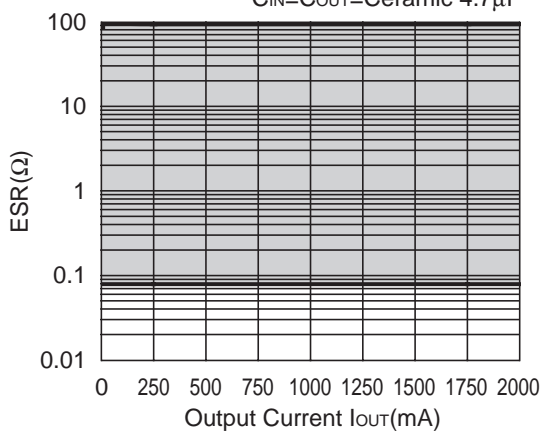
R1171S501x

$C_{IN}=C_{OUT}=\text{Ceramic } 2.2\mu\text{F}$



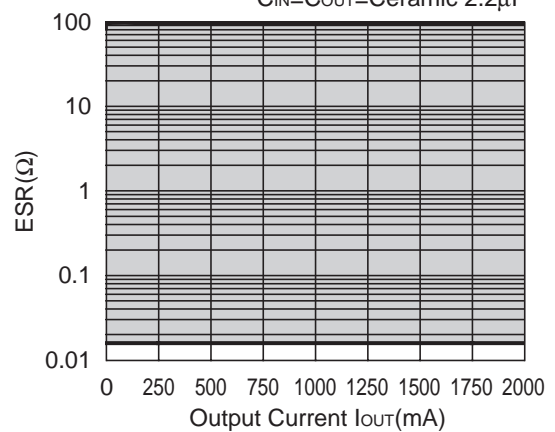
R1171J181x

$C_{IN}=C_{OUT}=\text{Ceramic } 4.7\mu\text{F}$

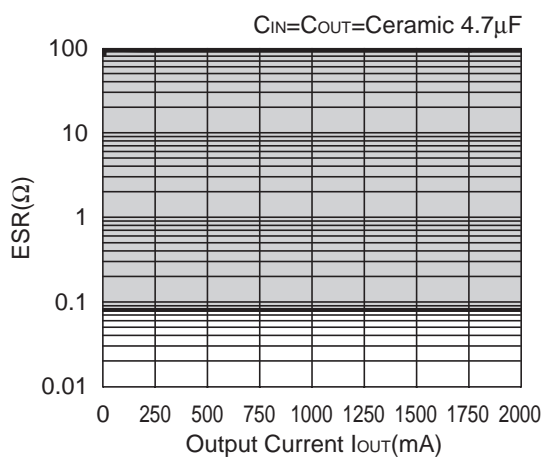


R1171J181x

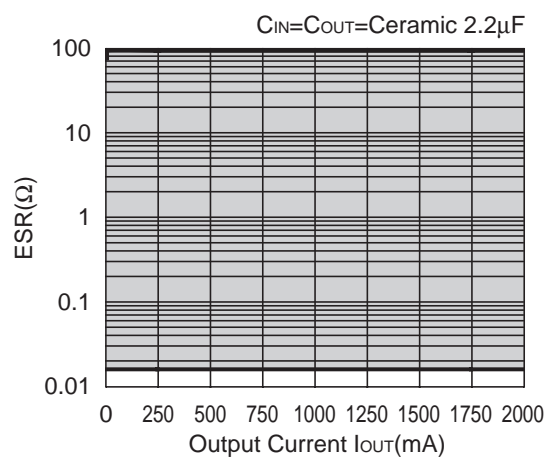
$C_{IN}=C_{OUT}=\text{Ceramic } 2.2\mu\text{F}$



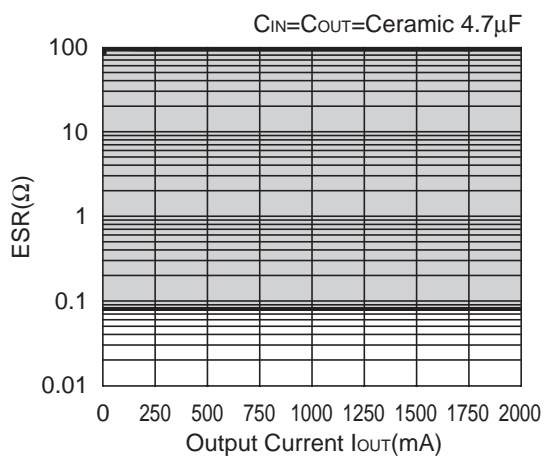
R1171J301x



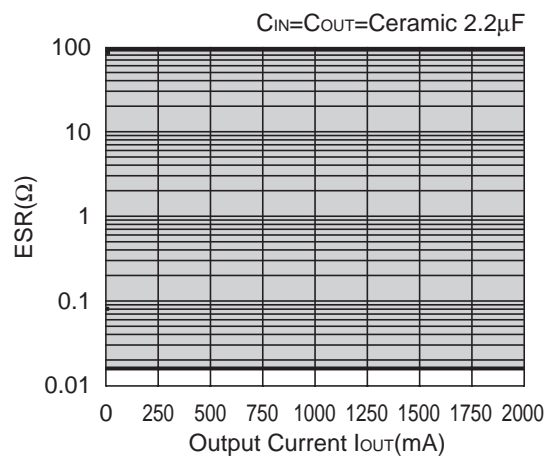
R1171J301x



R1171J501x



R1171J501x





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Sales & Support Offices

RICOH ELECTRONIC DEVICES CO., LTD.

Higashi-Shinagawa Office (International Sales)
3-32-3, Higashi-Shinagawa, Shinagawa-ku, Tokyo 140-8655, Japan
Phone: +81-3-5479-2857 Fax: +81-3-5479-0502

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Prof. W.H. Keesomlaan 1, 1183 DJ Amstelveen, The Netherlands
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RICOH ELECTRONIC DEVICES KOREA CO., LTD.

3F, Haesung Bldg. 504, Teheran-ro, Gangnam-gu, Seoul, 135-725, Korea
Phone: +82-2-2135-5700 Fax: +82-2-2051-5713

RICOH ELECTRONIC DEVICES SHANGHAI CO., LTD.

Room 403, No.2 Building, No.690 Bilbo Road, Pu Dong New District, Shanghai 201203,
People's Republic of China
Phone: +86-21-5027-3200 Fax: +86-21-5027-3299

RICOH ELECTRONIC DEVICES CO., LTD.

Taipei office
Room 109, 10F-1, No.51, Hengyang Rd., Taipei City, Taiwan (R.O.C.)
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Телефон: 8 (812) 309-75-97 (многоканальный)

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Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А